

# SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

## MCH6121 -— PNP Epitaxial Planar Silicon Transistor DC / DC Converter Amplifier

# **Applications**

· Relay drivers, lamp drivers, motor drivers, line switch

#### **Features**

- · Adoption of MBIT process
- · Low collector-to-emitter saturation voltage
- Ultrasmall-sized package permitting applied sets to be made small and slim (0.85mm)
- · Large current capacity
- · High speed switching
- · High allowable power dissipation · Halogen free compliance

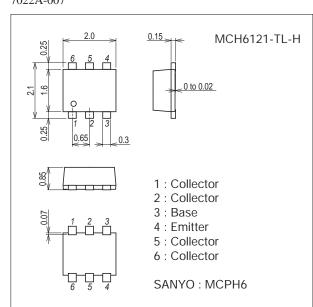
# **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		-15	V
Collector-to-Emitter Voltage	VCEO		-12	V
Emitter-to-Base Voltage	VEBO		-5	V
Collector Current	IC		-3	А
Collector Current (Pulse)	ICP		-5	А
Base Current	IB		-600	mA
Collector Dissipation	PC	When mounted on ceramic substrate (600mm <sup>2</sup> ×0.8mm)	1	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### **Package Dimensions**

unit: mm (typ) 7022A-007



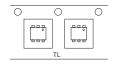
#### **Product & Package Information**

• Package : MCPH6

• JEITA, JEDEC : SC-88, SC-70-6, SOT-363

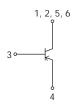
• Minimum Packing Quantity : 3,000 pcs./reel

#### Packing Type: TL Marking





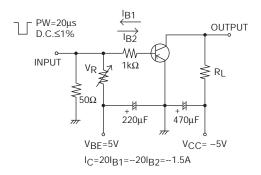
## **Electrical Connection**



#### Electrical Characteristics at Ta=25°C

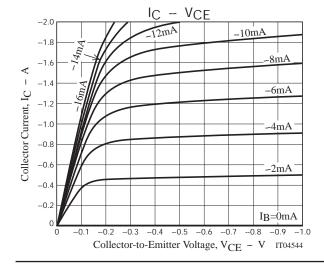
Parameter	Symbol	Conditions	Ratings			Linit
	Syllibol	Conditions	min	typ	max	Unit
Collector Cutoff Current	ICBO	V <sub>CB</sub> = -12V, I <sub>E</sub> =0A			-0.1	μΑ
Emitter Cutoff Current	IEBO	V <sub>EB</sub> = -4V, I <sub>C</sub> =0A			-0.1	μΑ
DC Current Gain	hFE	V <sub>CE</sub> = -2V, I <sub>C</sub> = -500mA	200		560	
Gain-Bandwidth Product	fT	V <sub>CE</sub> = -2V, I <sub>C</sub> = -500mA		380		MHz
Output Capacitance	Cob	V <sub>CB</sub> = -10V, f=1MHz		40		pF
Collector-to-Emitter Saturation Voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> = -1.5A, I <sub>B</sub> = -30mA		-110	-165	mV
Base-to-Emitter Saturation Voltage	V <sub>BE</sub> (sat)	I <sub>C</sub> = -1.5A, I <sub>B</sub> = -30mA		-0.85	-1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> = -10μA, I <sub>E</sub> =0A	-15			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC= -1mA, RBE=∞	-12			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I <sub>E</sub> = -10μA, I <sub>C</sub> =0A	-5			V
Turn-On Time	ton			30		ns
Storage Time	t <sub>stg</sub>	See specified Test Circuit.		90		ns
Fall Time	tf			14		ns

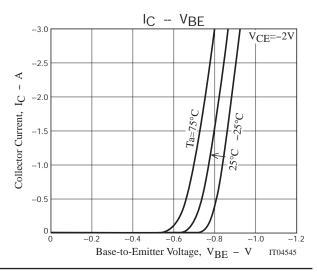
# **Switching Time Test Circuit**

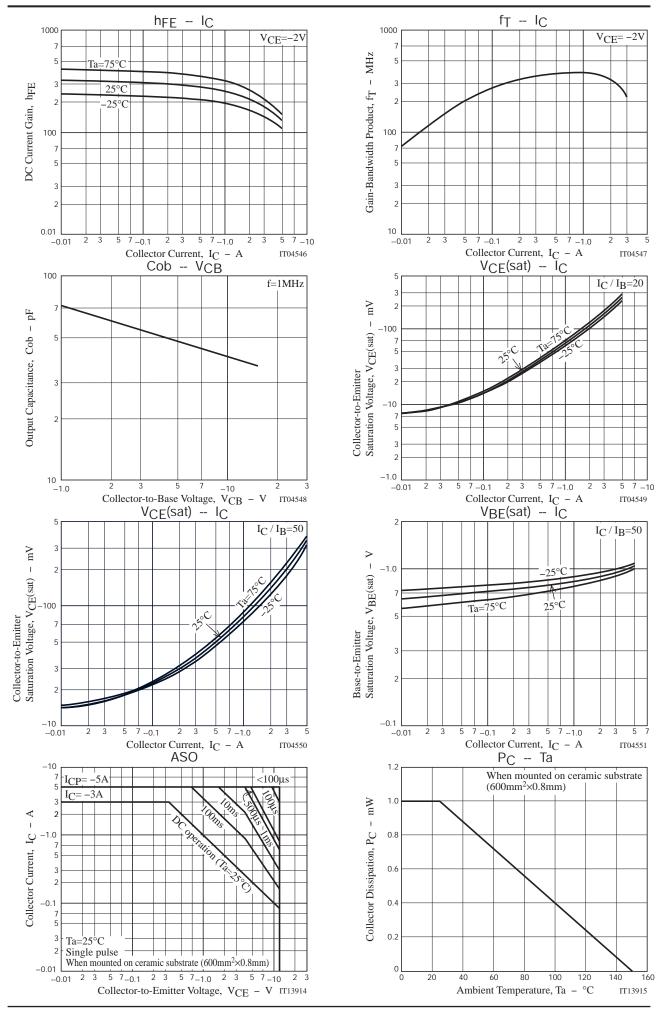


# **Ordering Information**

Device	Package	Shipping	memo	
MCH6121-TL-H	121-TL-H MCPH6		Pb Free and Halogen Free	





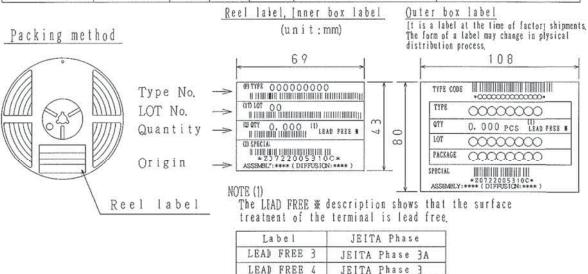


#### **Embossed Taping Specification**

#### MCH6121-TL-H

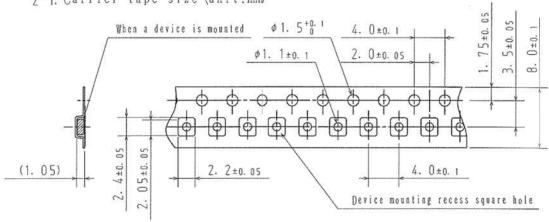
## 1. Packing Format

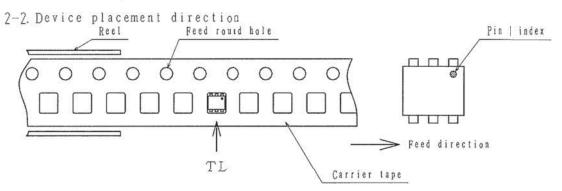
Package Name   Carrier Tap	Carrier Tape	Maximum Number of devices contained (scs)			Packing format		
	Туре	Reel	[nner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)	
МСРН6	MCP4	3, 000	15, 000	90, 000		6 inner boxes contained Dimensions:mm(external) 440×195×210	



## 2. Taping configuration

#### 2-1. Carrier tape size (unit:mm)

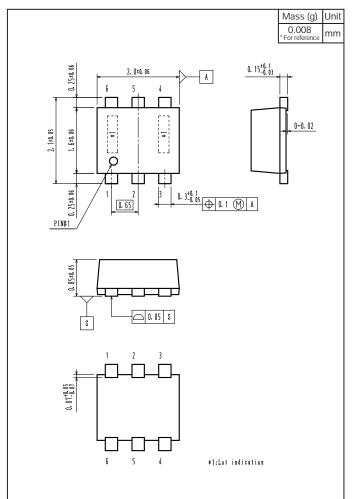




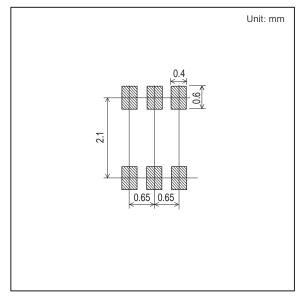
Those with pin 1 index on the feed hole side ·····TL

# **Outline Drawing**

# MCH6121-TL-H



# Land Pattern Example



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